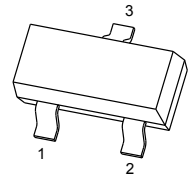


**SOT-23 Plastic-Encapsulate MOSFETS****CJ3402** N-Channel MOSFET

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
30V	55 mΩ@10V	4A
	70 mΩ@4.5V	
	110mΩ@2.5V	

SOT-23

1. GATE
2. SOURCE
3. DRAIN

DESCRIPTION

The CJ3402 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltage as low as 2.5V.

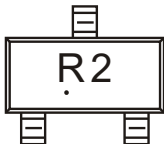
This device is suitable for use as a load switch or in PWM application.

FEATURES

- Lead free product is acquired
- Surface mount package

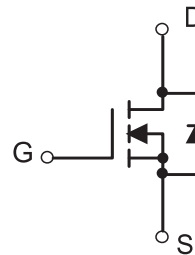
APPLICATION

- Load Switch and in PWM applications

MARKING

R2=Device code

Solid dot = Green molding compound device.

Equivalent Circuit**Maximum ratings ($T_a=25^{\circ}\text{C}$ unless otherwise noted)**

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	4	A
Pulsed Drain Current (note 1)	I_{DM}	15	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient (note 2)	$R_{\theta JA}$	357	$^{\circ}\text{C/W}$
Operation Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	$^{\circ}\text{C}$

MOSFET ELECTRICAL CHARACTERISTICS

$T_a=25^{\circ}\text{C}$ unless otherwise specified

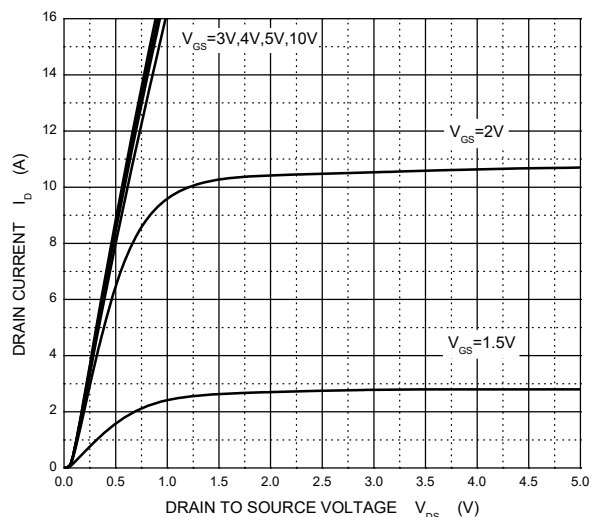
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =250μA	30			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =24V,V _{GS} = 0V			1	μA
Gate-body leakage current	I _{GSS}	V _{GS} =±12V, V _{DS} = 0V			100	nA
Gate threshold voltage (note 3)	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.6	0.85	1.4	V
Drain-source on-resistance (note 3)	R _{DS(on)}	V _{GS} =10V, I _D =4A		33	55	mΩ
		V _{GS} =4.5V, I _D =3A		39	70	mΩ
		V _{GS} =2.5V, I _D =2A		48	110	mΩ
Forward transconductance (note 3)	g _{FS}	V _{DS} =15V, I _D =4A		8		S
Diode forward voltage (note 3)	V _{SD}	I _S =1A, V _{GS} = 0V			1	V
DYNAMIC CHARACTERISTICS (note 4)						
Input capacitance	C _{iSS}	V _{DS} =15V,V _{GS} =0V,f =1MHz		390		pF
Output capacitance	C _{oSS}			54.5		pF
Reverse transfer capacitance	C _{rSS}			41		pF
Gate resistance	R _g	V _{DS} =0V,V _{GS} =0V,f =1MHz		3		Ω
SWITCHING CHARACTERISTICS (note 4)						
Turn-on delay time	t _{d(on)}	V _{GS} =10V,V _{DS} =15V, R _L =3.75Ω,R _{GEN} =6Ω		3.3		ns
Turn-on rise time	t _r			1		ns
Turn-off delay time	t _{d(off)}			21.7		ns
Turn-off fall time	t _f			2.1		ns
Total gate charge	Q _g	V _{DS} =15V,V _{GS} =4.5V,I _D =4A		4.34		nC
Gate-source Charge	Q _{gs}			0.6		nC
Gate-drain Charge	Q _{gd}			1.38		nC
Body diode reverse recovery time	t _r	I _F =4A,dI/dt=100A/μs		1.2		ns
Body diode reverse recovery charge	Q _{rr}			6.3		nC
Reverse Diode Characteristics						
Drain-source diode forward voltage	I _S			4		A
Continuous drain-source diode forward current	I _{SM}			15		A

Notes :

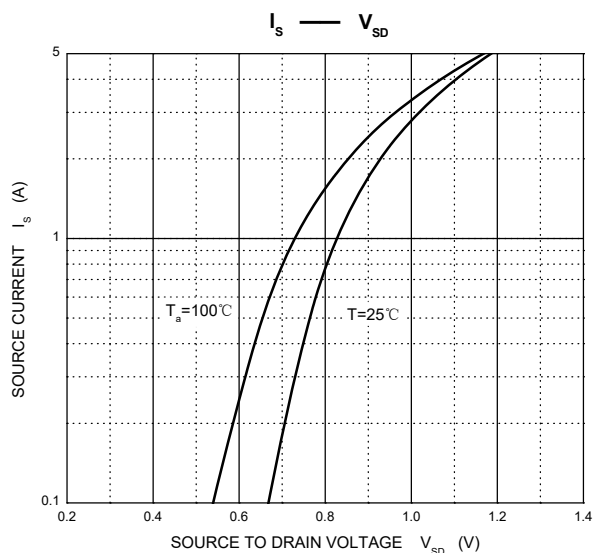
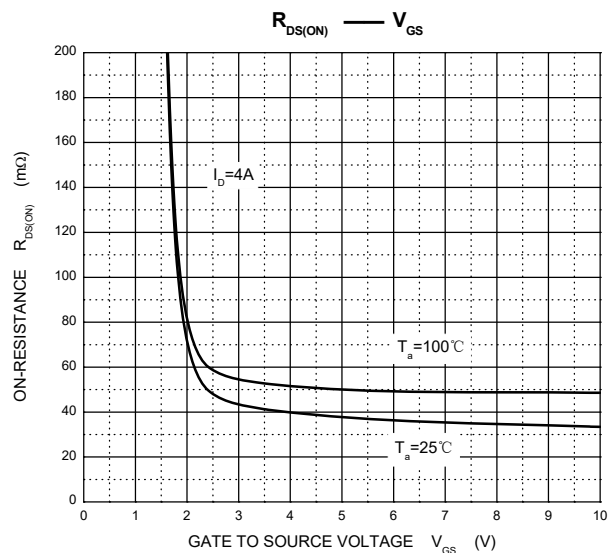
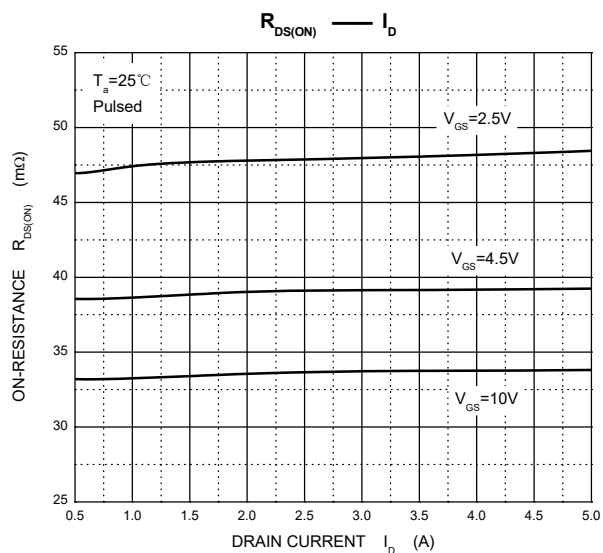
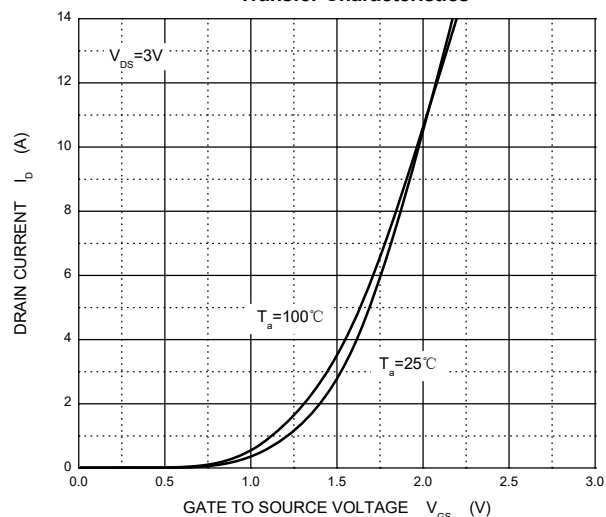
1. Repetitive rating : Pulse width limited by junction temperature.
2. Surface mounted on FR4 board , $t \leq 10s$.
3. Pulse Test : Pulse Width $\leq 80\mu s$, Duty Cycle $\leq 0.5\%$.
4. Guaranteed by design, not subject to producing.

Typical Characteristics

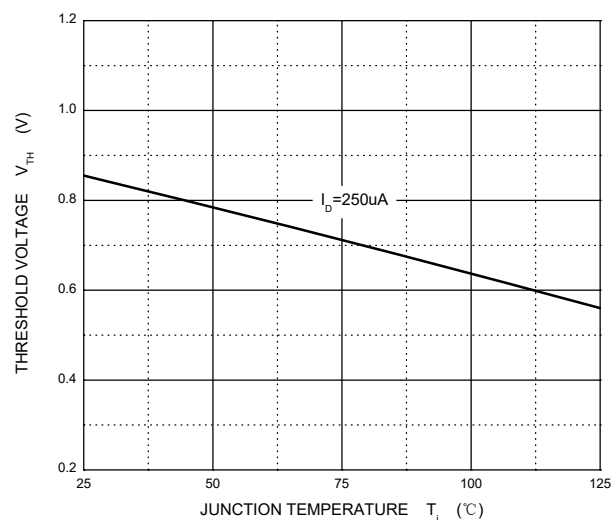
Output Characteristics



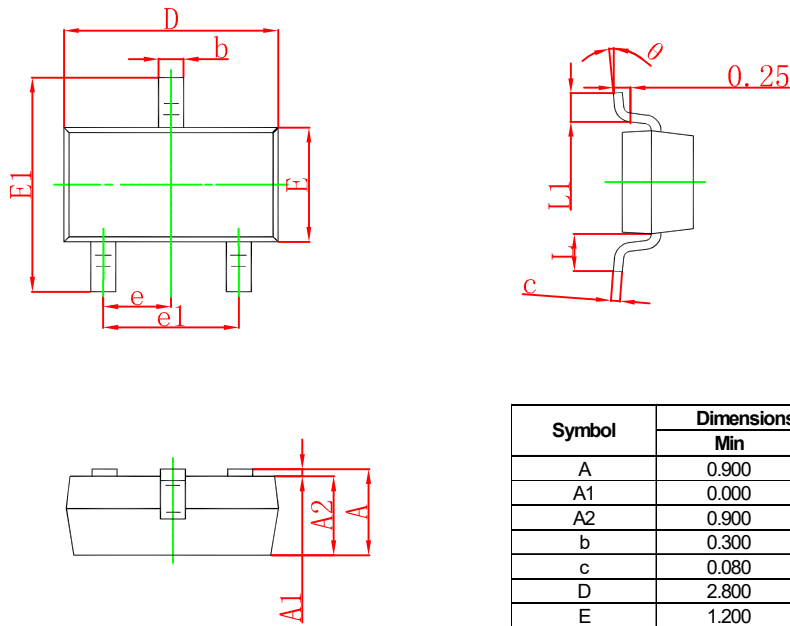
Transfer Characteristics



Threshold Voltage

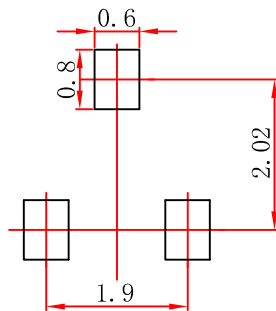


SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



Note:

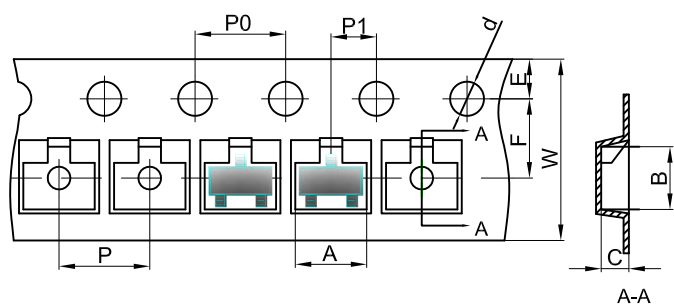
1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape

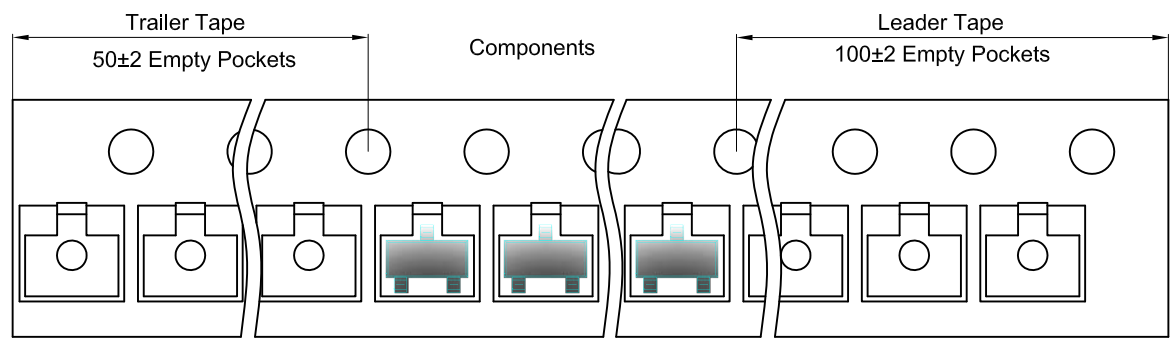


Packaging Description:

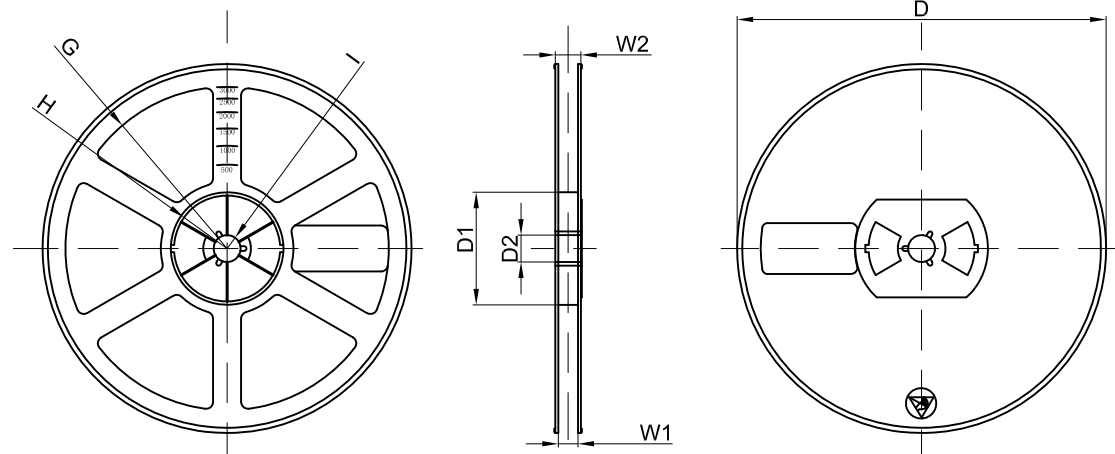
SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer



SOT-23 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	45,000 pcs	203×203×195	180,000 pcs	438×438×220	